



## **Product Summary**

Device	BV <sub>DSS</sub>	Rds(on) Max	I <sub>D</sub> Max Tc = +25°C
Q1& Q2	30V	11.1mΩ @ Vgs = 10V	30A
	30 V	15.0mΩ @ V <sub>GS</sub> = 4.5V	25A

### Description

This new generation MOSFET is designed to minimize the on-state resistance ( $R_{DS(ON)}$ ) yet maintain superior switching performance, making it ideal for high efficiency power management applications.

## **Applications**

- General Purpose Interfacing Switch
- Power Management Functions

#### **DUAL N-CHANNEL ENHANCEMENT MODE MOSFET**

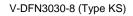
### **Features and Benefits**

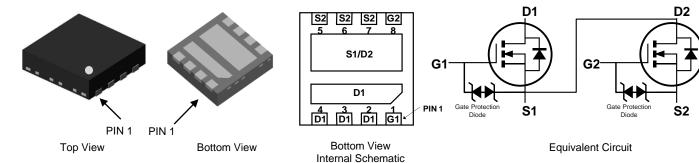
- Ultra Low Gate Threshold Voltage
- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- ESD Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

### **Mechanical Data**

- Case: V-DFN3030-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu over Copper Leadframe. Solderable per MIL-STD-202, Method 208 <sup>(A)</sup>
- Weight: 0.02 grams (Approximate)







### Ordering Information (Note 4)

Part Number	Case	Tape Width	Tape Pitch	Packaging
DMT3009UDT-7	V-DFN3030-8 (Type KS)	12mm	8mm	1,500/Tape & Reel

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

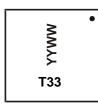
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



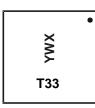
## **Marking Information**

Site 1



T33= Product Type Marking Code YYWW = Date Code Marking YY or YY= Last Two Digits of Year (ex: 20 = 2020) WW = Week Code (01 to 53)

Site 2



T33 = Product Type Marking Code YWX = Date Code Marking Y = Year (ex: H = 2020) W = Week (ex: a = Week 27; z Represents Week 52 and 53) X = Internal Code (ex: U = Monday)

#### Date Code Key

Year	2019	2020	2021	2022	2023	2024	2025	2026	2027	2028	2029	2030
Code	G	Н	_	J	K	L	М	Ν	0	Р	R	S
Week		1-2	26			27-	-52			5	53	
Code	A-Z				a-z			z				
Internal Code	Su	n	Mon		Tue	v	Ved	Thu		Fri		Sat
Code	Т		U		V		W	Х		Y		Z



## Maximum Ratings ( $@T_J = +25^{\circ}C$ , unless otherwise specified.)

Characteristic	Symbol	Q1&Q2	Unit		
Drain-Source Voltage	Vdss	30	V		
Gate-Source Voltage			Vgss	±12	V
Continuous Drain Current (Note 6) V <sub>GS</sub> = 10V	Steady State	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	ID	10.6 8.5	А
Continuous Drain Current (Note 7) V <sub>GS</sub> = 10V	Steady State	Tc = +25°C Tc = +70°C	ID	30 25	А
Maximum Body Diode Forward Current (Note 6)	•	•	ls	2.1	А
Pulsed Drain Current (100µs Pulse, Duty Cycle = 1%	)		Ідм	80	A
Pulsed Body Diode Forward Current (100µs Pulse, D	I <sub>SM</sub>	80	А		
Avalanche Current (Note 8) L = 0.1mH	las	19	А		
Avalanche Energy (Note 8) L = 0.1mH			E <sub>AS</sub>	18	mJ

## Thermal Characteristics (@T<sub>J</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	T <sub>A</sub> = +25°C	PD	1.1	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	R <sub>0</sub> JA	112	°C/W
Total Power Dissipation (Note 6)	T <sub>A</sub> = +25°C	PD	1.9	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	RθJA	66	°C/W
Total Power Dissipation (Note 7)	Tc = +25°C	PD	16	W
Thermal Resistance, Junction to Case (Note 7)		Rejc	8	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	С°

## Electrical Characteristics (@T<sub>J</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 9)	Cymber		.,,,,	max	Unit	
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	30	_	_	V	$V_{GS} = 0V, I_D = 250 \mu A$
Zero Gate Voltage Drain Current	IDSS		_	1	μA	$V_{DS} = 24V, V_{GS} = 0V$
Gate-Source Leakage	lgss		—	±10	μA	$V_{GS} = \pm 10V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 9)						
Gate Threshold Voltage	Vgs(th)	0.5	—	1.8	V	$V_{DS} = V_{GS}$ , $I_D = 250 \mu A$
Static Drain-Source On-Resistance	Descent	_	8.6	11.1	mΩ	$V_{GS} = 10V, I_D = 11A$
Static Drain-Source On-Resistance	RDS(ON)	_	11.5	15	1115.2	V <sub>GS</sub> = 4.5V, I <sub>D</sub> = 7A
Diode Forward Voltage	Vsd	_	0.8	1.2	V	VGS = 0V, IS = 8.8A
DYNAMIC CHARACTERISTICS (Note 10)						
Input Capacitance	Ciss		894			
Output Capacitance	Coss	_	381	_	pF	$V_{DS} = 15V, V_{GS} = 0V, f = 1.0MHz$
Reverse Transfer Capacitance	Crss	_	76	_		
Gate Resistance	Rg	_	1.1	—	Ω	$V_{DS} = 0V$ , $V_{GS} = 0V$ , $f = 1.0MHz$
Total Gate Charge (V <sub>GS</sub> = 10V)	Qg	_	14.6			
Total Gate Charge (V <sub>GS</sub> = 4.5V)	Qg	_	7.4	—	nC	Vps = 15V. lp = 10A
Gate-Source Charge	Qgs	_	1.6	_		$v_{DS} = 15v, ID = 10A$
Gate-Drain Charge	Qgd		3.4			
Turn-On Delay Time	t <sub>D(ON)</sub>	_	3.4	_		
Turn-On Rise Time	tR	_	5.5	_		$V_{GS} = 10V, V_{DD} = 15V, R_g = 1\Omega,$
Turn-Off Delay Time	tD(OFF)		9.6	_	ns	I <sub>D</sub> = 8.8A
Turn-Off Fall Time	tF		1.6		1	
Body Diode Reverse Recovery Time	trr		17	_	ns	
Body Diode Reverse Recovery Charge	Qrr		6.7		nC	IF = 8.8A, di/dt = 100A/μs

 Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
Thermal resistance from junction to soldering point (on the exposed drain pad). Notes:

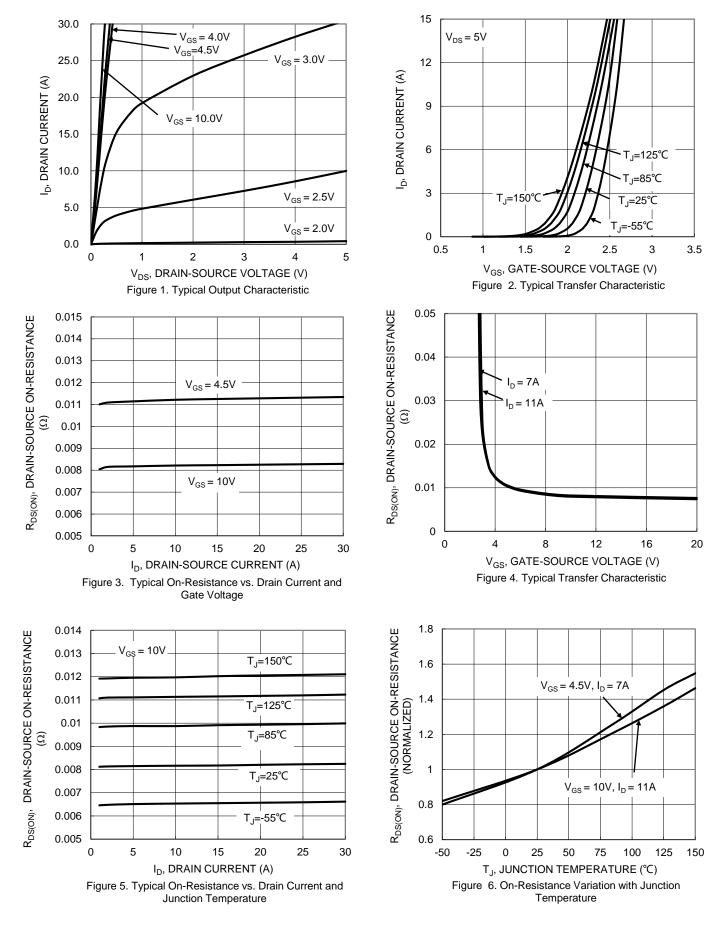
8. UIS in production with L = 0.1mH, starting  $T_A = +25^{\circ}C$ .

9. Short duration pulse test used to minimize self-heating effect.

10. Guaranteed by design. Not subject to product testing.

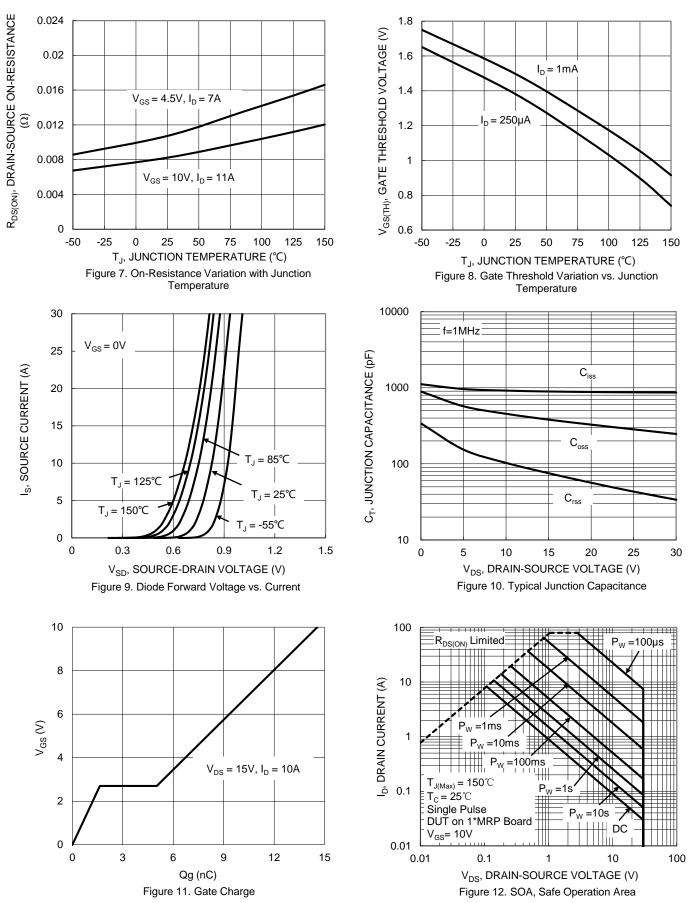


## **DMT3009UDT**

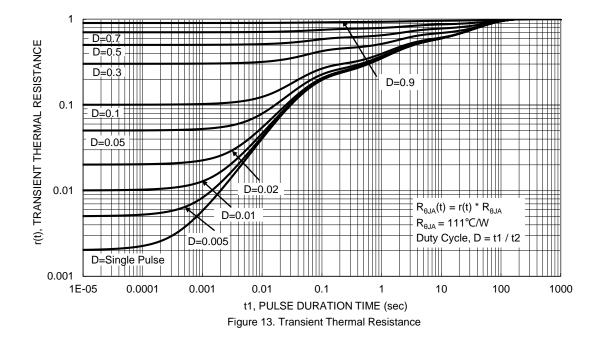




## DMT3009UDT



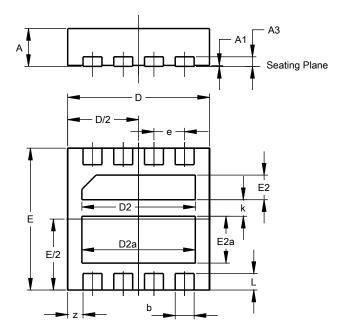






## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.



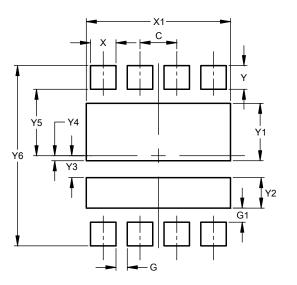
V-DEN2020-9	(Typo	KG)
V-DFN3030-8	(iype	ng)

		2020.0					
V-DFN3030-8 (Type KS)							
Dim	Min	Max	Тур				
Α	0.77	0.85	0.80				
A1	0.00	0.05	0.02				
A3	0	).20BSC	)				
b	0.35	0.45	0.40				
D	2.95	3.050	3.00				
D2	2.30	2.50	2.40				
D2a	2.30	2.50	2.40				
E	2.95	3.050	3.00				
E2	0.42	0.62	0.52				
E2a	0.89	1.09	0.99				
е	0.65BSC						
k	-	-	0.35				
L	0.30	0.40	0.35				
z	0.325BSC						
All	All Dimensions in mm						

# Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### V-DFN3030-8 (Type KS)



Dimensions	Value (in mm)
С	0.650
G	0.200
G1	0.250
Х	0.450
X1	2.550
Y	0.420
Y1	1.019
Y2	0.541
Y3	0.389
Y4	0.089
Y5	1.180
Y6	3.200



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